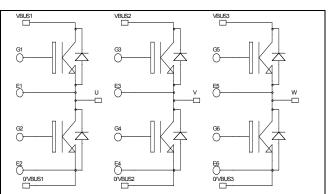


Triple phase leg NPT IGBT Power Module



VBUS2

no/vbus2

VBUS3

0/VBUS3

 $V_{CES} = 1200V$ $I_C = 50A @ Tc = 80°C$

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) FAST IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a phase leg of three times the current capability
- Module can be configured as a three phase bridge
- Module can be configured as a boost followed by a full bridge
- RoHS compliant



Absolute maximum ratings

D/VBUS1

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
I_{C}	Continuous Collector Current	$T_c = 25^{\circ}C$	75	
	Continuous Conector Current	$T_c = 80^{\circ}C$	50	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	150	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	312	W
RBSOA	Reverse Bias Safe Operating Area	$T_{j} = 150^{\circ}C$	100A @ 1200V	•

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Ţ	Zara Cata Valtaga Callactar Current	$V_{GE} = 0V$	$T_i = 25^{\circ}C$			250	4
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 1200V$	$T_{i} = 125^{\circ}C$			500	μΑ
***	C. II. day Farittan and anti-m Walkers	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		3.2	3.7	V
$V_{CE(sat)}$	Collector Emitter saturation Voltage	$I_C = 50A$	$T_j = 125$ °C		4.0		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1 \text{ mA}$		4.5		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20 \text{ V}, V_{CE} = 0 \text{ V}$				100	nA

Dynamic Characteristics

·	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			3450		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			330		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			220		
Q_{g}	Total gate Charge	$V_{GS} = 15V$			330		nC
Q_{ge}	Gate – Emitter Charge	$V_{Bus} = 600V$			35		
Q_{gc}	Gate – Collector Charge	$I_C = 50A$			200		
T _{d(on)}	Turn-on Delay Time	Inductive Switch	hing (25°C)		35		
T_{r}	Rise Time	$V_{GE} = 15V V_{Bus} = 600V I_{C} = 50A R_{G} = 5 \Omega$			65		ns
$T_{d(off)}$	Turn-off Delay Time				320		
T_{f}	Fall Time				30		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 50A$ $R_{G} = 5 \Omega$			35		ns
$T_{\rm r}$	Rise Time				65		
$T_{d(off)}$	Turn-off Delay Time				360		
$T_{\rm f}$	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		6.9		I ma I
E_{off}	Turn-off Switching Energy	$I_{C} = 50A$ $R_{G} = 5 \Omega$	$T_j = 125$ °C		3.05		mJ

Chopper diode ratings and characteristics

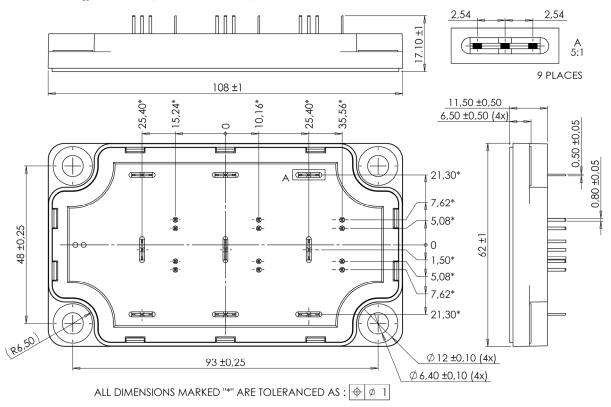
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$			250 500	μΑ
I_{F}	DC Forward Current		$Tc = 70^{\circ}C$		60		A
	Diode Forward Voltage	$I_F = 60A$			2.0	2.5	V
V_{F}		$I_{\rm F} = 120A$			2.3		
		$I_F = 60A$	$T_j = 125$ °C		1.8		
t _{rr}	Reverse Recovery Time	$I_F = 60A$ $V_R = 800V$	$T_j = 25$ °C		400		
			$T_{j} = 125^{\circ}C$		470		ns
Q _{rr}	Reverse Recovery Charge		$T_j = 25$ °C		1200		nC
		$T_j = 125$ °C			4000		IIC



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.4	°C/W
			Diode			0.9	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_J	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

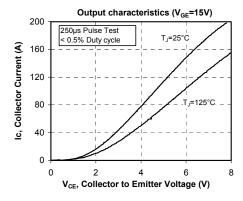
SP6-P Package outline (dimensions in mm)

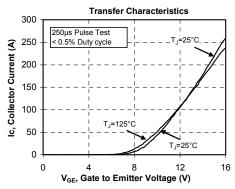


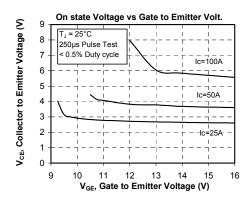
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

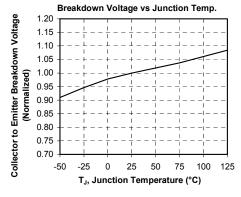


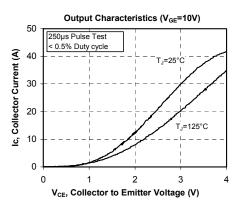
Typical Performance Curve

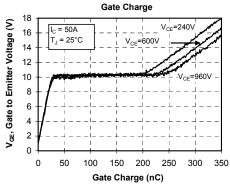


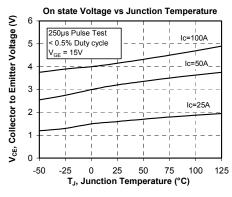


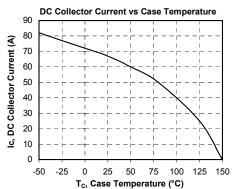




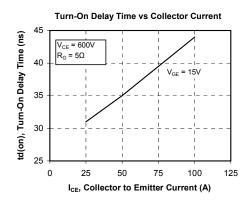


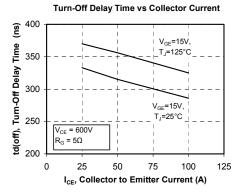


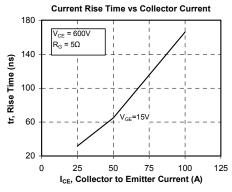


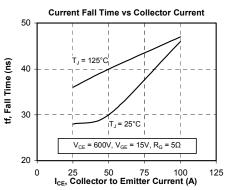


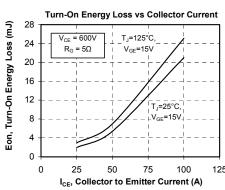


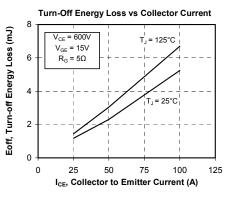


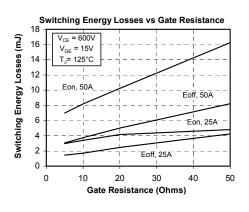




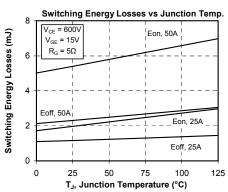






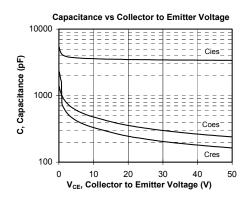


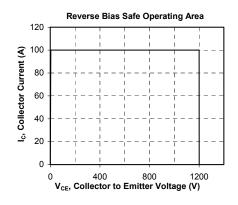
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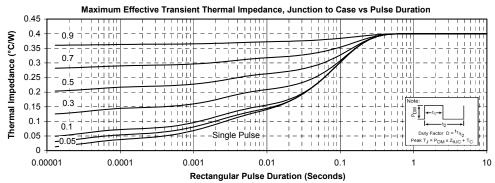


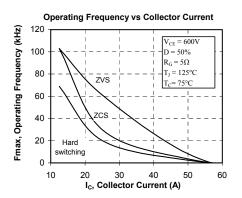
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